

## Reconstruction of moiré lattices in twisted transition metal dichalcogenide bilayers

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## Introduction

 Moiré patterns created with transition metal dichalcogenides can host correlated electronic phases, long-lived excitons, phasons.

 An important step to understand the novel electronic, optical, and vibrational properties is the incorporation of structural relaxation effects.



To date, all studies conducted on moiré patterns presume that the moiré lattice constant before and after relaxation are identical.

Questions addressed

Can there be novel lattice reconstruction?

What are the consequences of such reconstruction on electronic properties ?

Long-range order of the moire lattices



Radial distribution function at moire scale, g<sub>m</sub>(r) using both standard relaxation (SR) and simulated annealing (SA).
Evidence of lattice reconstruction as θ>58.4<sup>0</sup>



Examples of other possible transient structures found with simulated annealing (SA) which can be metastable in experiments.

## Impact of lattice reconstruction on electronic band structure



Conclusions

The presumption that the moiré lattice constnat of the rigidly twisted structure continues to characterize the relaxed twisted structure is in general invalid.
The lattice reconstruction

The lattice reconstruction significantly modifies the electronic band structure.
These lattice reconstruction for

small twist angles near 60° is 1e-04 6.10 generic to any transition metal 30 10 30 300 20 Ũ 20 10 20 30 20 300 20 30 20 10 10 10 x (nm) x (nm) dichalcogenides and their x (nm) x (nm) x (nm) x (nm) (a),(b) Electronic band structures near the band edges of a  $\sqrt{3}x\sqrt{3}x1$  supercell of tBLMoS<sub>2</sub> for 58.47° for unheterostructures. reconstructed and lattice reconstructed structures, respectively. The supercell is marked with black dashed lines Multiple flat-bands can host a in (d),(g), respectively. (c) Colors used to denote stackings in (e)-(f),(h)-(l).  $|\psi_r(r)|^2$  of the states near valence rich variety of correlated electronic phases. band maximum, and near conduction band minimum for structures obtained with SR ((e)-(f)) and with SA ((h)-(l))

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**References:** 

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